

# DC COMPONENTS CO., LTD.

### RECTIFIER SPECIALISTS

1N914 THRU <sup>1N</sup> / <sup>1N</sup> 4148 / 4454

## TECHNICAL SPECIFICATIONS OF HIGH SPEED SWITCHING DIODES

VOLTAGE RANGE -50 to 100 Volts

CURRENT - 0.075 to 0.2 Ampere

#### **FEATURES**

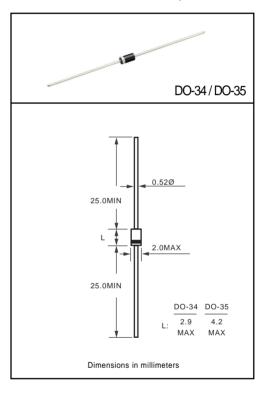
- \* Silicon epitaxial planar diodes
- \* Low power loss, high efficiency
- \* Low leakage
- \* Low forward voltage
- \* High speed switching
- \* High current capability
- \* High reliability

#### MECHANICAL DATA

- \* Case: Glass sealed case
- \* Lead: MIL-STD-202E, Method 208 guaranteed
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any
- \* Weight: 0.13 gram

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

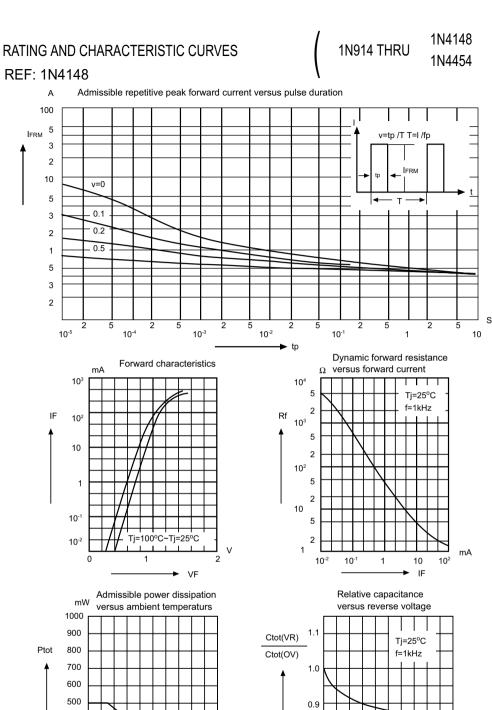
Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

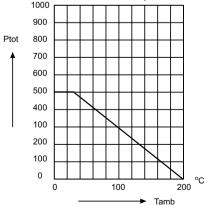


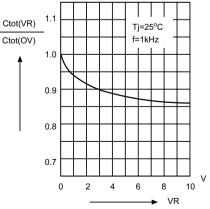
	SYMBOL	1N914	1N4148	1N4150	1N4151	1N4154	1N4448	1N4454	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	100	100	50	75	35	100	75	V
Maximum Average Rectified Current	lo	75	150	200	150	150	150	150	mA
Maximum Power Dissipation Tamb=25°C	Ptot	250	500	500	500	500	500	500	mW
Maximum Forward Voltage	VF	1.0/10	1.0/10	1.0/200	1.0/50	1.0/30	1.0/100	1.0/10	V/mA
Maximum Reverse Current	IR	5000/75	5000/75	100/50	50/50	100/25	5000/75	100/10	nA/V
Maximum Reverse Recovery Time	trr	4.0	4.0	4.0	2.0	2.0	4.0	4.0	nS
Typical Junction Capacitance	Cı	4.0							pF
Operating and Storage Temperature Range	TJ,TSTG	-65 to + 200							°C

NOTE: 1-1N914A, 1N914B IS SAME AS 1N914, EXCEPT DIFFERENT IN FORWARD VOLTAGE:

- 1N914A-1.0/20 V/mA
- 1N914B-1.0/100 V/mA
- 2.Suffix "M" stands for "DO-34" package.(e.g.:1N4148M)









DC COMPONENTS CO., LTD.

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.